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Vishay Semiconductors

High Performance Schottky Rectifier, 3 A



DO-214AC (SMA)

PRODUCT SUMMARY				
Package	DO-214AC (SMA)			
I _{F(AV)}	3 A			
V_{R}	40 V			
V _F at I _F	0.46 V			
I _{RM}	20 mA at 125 °C			
T _J max.	150 °C			
Diode variation	Single die			
E _{AS}	6.0 mJ			

FEATURES

- Extremely low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability
- Surface mountable
- Compact size
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

APPLICATIONS

- Switching power supplies
- Meter protection
- · Reverse protection for power input to PC board circuits
- · Battery isolation and charging
- · Low threshold voltage diode
- Freewheeling or by-pass diode
- Low voltage clamp

DESCRIPTION

The VS-30MQ040-M3 Schottky rectifier is designed to be used for low power applications where a reverse voltage of 40 V is encountered and surface mountable is required.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I _{F(AV)}	Rectangular waveform	3	A	
V _{RRM}		40	V	
I _{FSM}	t _p = 5 μs sine	330	А	
V _F	2 A _{pk} , T _J = 125 °C	0.43	V	
T _J	Range	-40 to +150	°C	

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-30MQ040-M3	UNITS
Maximum DC reverse voltage	V _R	40	V
Maximum working peak reverse voltage	V_{RWM}	40	V

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 4	I _{F(AV)}	$I_{F(AV)}$ 50 % duty cycle at T_L = 89 °C, rectangular waveform On PC board 9 mm ² island (0.013 mm thick copper pad area)		3	Α
Maximum peak one cycle non-repetitive surge current		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	330	Α
See fig. 6	I _{FSM}	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	140	A
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 12 mH		6.0	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical		1.0	Α



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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop		1 A	T _J = 25 °C	0.42	V
	V _{FM} ⁽¹⁾	3 A		0.51	
See fig. 1	V _{FM} (·)	1 A	T _J = 125 °C	0.34	
		3 A		0.46	
Maximum reverse leakage current See fig. 2	,	T _J = 25 °C	V _R = Rated V _R	0.5	- mA
	IRM	T _J = 125 °C		20	
Threshold voltage	V _{F(TO)}	T _J = T _J maximum		0.26	V
Forward slope resistance	r _t			64.6	mΩ
Typical junction capacitance	C _T	V _R = 10 V _{DC} , T _J = 25 °C, test signal = 1 MHz		134	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		2.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R 10		10 000	V/µs

Note

 $^{(1)}\,$ Pulse width = 300 $\mu s,$ duty cycle = 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 40 to 150	°C
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	80	°C/W
Approximate weight			0.07	g
Approximate weight		0.002	OZ.	
Marking device		Case style SMA (similar D-64)	3	F

Note

$$^{(1)} \quad \frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$$



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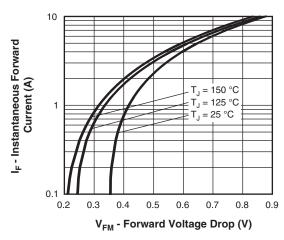


Fig. 1 - Maximum Forward Voltage Drop Characteristics

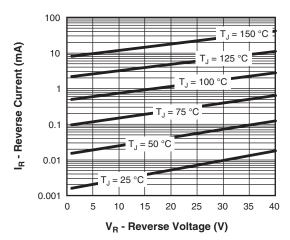


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

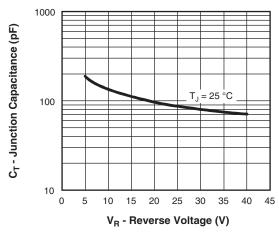
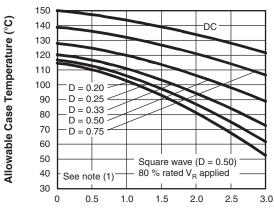


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



I_{F(AV)} - Average Forward Current (A)

Fig. 4 - Maximum Average Forward Current vs. Allowable Lead Temperature

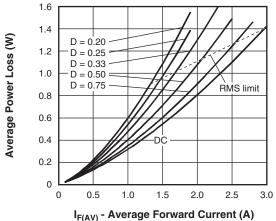
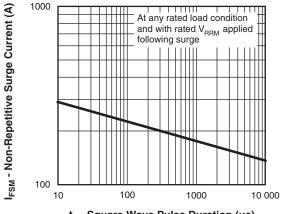


Fig. 5 - Maximum Average Forward Dissipation vs. Average Forward Current



t_p - Square Wave Pulse Duration (μs)

Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

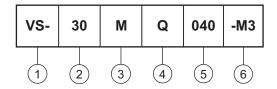
(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}$; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R



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ORDERING INFORMATION TABLE

Device code



- Vishay Semiconductors product
- 2 Current rating
- 3 M = SMA
- 4 Q = Schottky "Q" series
- 5 Voltage rating (040 = 40 V)
- 6 Environmental digit:

-M3 = halogen-free, RoHS-compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	PREFERRED PACKAGE CODE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-30MQ040-M3/5AT	5AT	7500	13" diameter plastic tape and reel		

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95400			
Part marking information	www.vishay.com/doc?95403			
Packaging information	www.vishay.com/doc?95404			

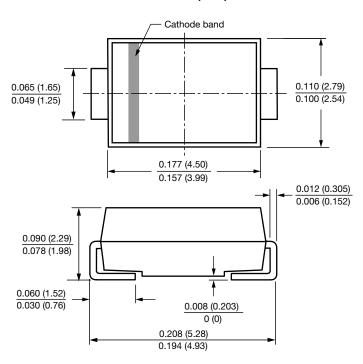


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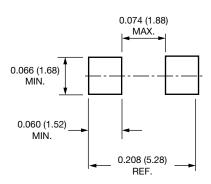
SMA

DIMENSIONS in inches (millimeters)

DO-214AC (SMA)



Mounting Pad Layout





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